



INTERNATIONAL
GEMOLOGICAL
INSTITUTE

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LABORATORY GROWN DIAMOND REPORT

October 19, 2026

IGI Report Number

DESCRIPTION

SHAPE AND CUTTING STYLE

MEASUREMENTS

GRADING RESULTS

CARAT WEIGHT

COLOR GRADE

CLARITY GRADE

ADDITIONAL GRADING INFORMATION

POLISH

SYMMETRY

FLUORESCENCE

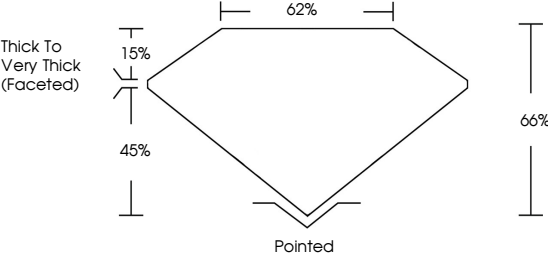
INSCRIPTION(S)

COMMENTS: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process. Type IIa

LG848668584

Report verification at [igi.org](#)

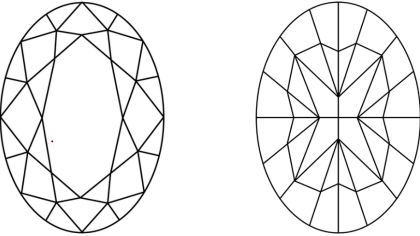
PROPORTIONS





Sample Image Used

CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.

COLOR

D E F G H I J Faint Very Light Light

CLARITY

FL IF VS 1-2 VS 1-2 SI 1-2 I 1-3

Flawless Internally Flawless Very Very Slightly Included Very Slightly Included Slightly Included Included

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LABORATORY GROWN DIAMOND

OVAL MODIFIED BRILLIANT

15.52 X 8.99 X 5.93 MM

6.10 CARATS

D

VVS 2

EXCELLENT

EXCELLENT

NONE

IGI LG848668584



IGI

October 19, 2026

IGI Report No LG848668584

OVAL MODIFIED BRILLIANT

15.52 X 8.99 X 5.93 MM

6.10 CARATS

D

VVS 2

D

66%

62%

Thick to Very Thick (Faceted)

Pointed

EXCELLENT

EXCELLENT

NONE

IGI LG848668584

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